



Docket No.: 50090-233

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Yukihiro NAGAI, et al.

Serial No.: 09/631,623

Group Art Unit: 2811

Filed: August 04, 2000

Examiner: D. Kang

For: SEMICONDUCTOR DEVICE HAVING A POTENTIAL FUSE, AND METHOD  
OF MANUFACTURING THE SAME

AMENDMENT UNDER 37 C.F.R. §1.116

Commissioner for Patents  
Washington, DC 20231

Sir:

The following Amendment and Remarks are submitted in response to the Office  
Action dated June 5, 2002, pursuant to the provisions of 37 C.F.R. §1.116.

IN THE CLAIMS

Please amend claims 2 and 3 as follows:

--2. (Twice Amended) The semiconductor device according to claim 1,

further comprising:

a plurality of surface insulating films[, having different thicknesses,] formed on a  
surface of the active regions in the first portion and on the interior surface of said at least  
one trench in the second portion; and

a plurality of conductive films formed on each of the surface insulating films in  
the first portion;

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